Quantum Nano Fabrication and Characterization Facility

6/6/24

IAFL Open House and RAC Capabilities

Nathan Nelson-Fitzpatrick







INTRODUCTION AND LAB USE UPDATE

Core facility nanofabrication/characterization lab

- Resources in QNC Cleanroom, QNC Metrology and RAC1/2 buildings
- 14 staff 11 provide technical services

214 users / year from 84 groups (FY24)

- 73% UWaterloo internal
- 17% SME / industry
- 10% External academic
- > 43000 hours invoiced / year (FY24)
 - >\$2.0M generated/year to support maintenance
 - SME users accounted for 47% of revenue
- Open to academic and industrial/SME users
 - QNFCF members own their own IP







COMMUNITY & HOP DEVELOPMENT

Individual training is part of our DNA

- >1000 hours of training delivered per year
- Over 95% of equipment available for user training
 - Including 100kV EBL and S/TEM
- 1-1 staff driven training for equipment
- Regular opportunities for learning from staff, industry professionals and other lab users
- Professional staff resources for guidance in troubleshooting and process development





Top: TEM "Lunch and Learn" lecture **Bottom left:** WIN-Bristol summer school **Bottom right:** BEAMER CAD software workshop





QNFCF 2024 MAJOR PROJECTS REVIEW



NEMO lab management

Project lead: **Greg Holloway** Supporting staff: Nicki Shaw, Nathan Nelson-Fitzpatrick, Guillermo Gomez



S/TEM, FIB, sample prep

Project lead: **Nicki Shaw** Supporting staff: Sandra Gibson, Greg Holloway, Daphene Wen (co-op)



Inert Atmosphere Fabrication Lab

Project lead: **Taso Alkiviades** Supporting staff: John Nugent, Greg Holloway, Lino Eugene, Nathan Nelson-Fitzpatrick





TEM

(L) Vasily Panferov, Professor Juewen Liu (R) Mohamed Okasha, Professor Vivek Maheshwari Department of Chemistry, University of Waterloo



STEM

Yu Shi, Professor Guoxing Miao, Department of Electrical and Computer Engineering, University of Waterloo



Diffraction

Ahmed Elbaroudy, Professor Zbigniew Wasilewski, Molecular Beam Epitaxy Research Group (MBE), University of Waterloo



Spectroscopy

Yu Shi, Professor Guoxing Miao, Department of Electrical and Computer Engineering, University of Waterloo



OF TEM USERS ARE **TRAINED** TO



Training hours delivered Since October 2023







JEOL

ONFCF TEM TEAM

(PROC): Wedge Polishing Author: Daphene Wen Date credit: December 18, 2023 Filename: Proc. Wedge, Polishing pdf Image: Proc. Wedge, Polishing pdf Image: Proc. Wedge, Polishing pdf Image: Proc. Wedge, Polishing pdf Image: Polishing pdf Jummary: Image: Polishing of the same interparting semiconductor samples valued ge polishing to be viewed in the TEM. Southers: Polishing on Allied Multiprep 1 2.1 Calibration 3 7 2.3 Polish Side 8 7 7 2.4 Fatter sample ond pyrex stub 7 7 2.5 Polish Side 8 3 7 2.5 Polish Side 8 3 9 3 2.5.2 Polish Me sample with colloidal silica 3 9 2.5.3 Polish Side 8 30 30 4 Patter sample onto Moring 30 30 5 Polish Side Analytic Mit Colloidal silica 30 30 6 Wedge polish Bide Analytic Mit Colloidal silica 30 30 7 Patter sample onto Moring 30	Process Bafar	FCF or deficiency tradem or facility	
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Co-op Daphene Wen



 1 µm
 Signal A = InLens
 Mag =
 12.31 K X
 Focus =
 5.1 mm
 EHT =
 5.00 kV
 Brightness =
 49.6 %

 FIB
 FIB Mag =
 522 X
 FIB Focus =
 0.0
 FIB EHT =
 0.00 kV
 Contrast =
 36.5 %

FIB manipulation of InP nanowire



Top: Sandra Gibson **Right:** Nicki Shaw and Greg Holloway



Zeiss FIB & example TEM lamellae









Mechanical sample prep project

EXTRA RAC RESOURCE - PULSED LASER DEPOSITION TO

Transformative Quantum Technologies



Pulsed Laser Deposition

- UHV construction
- 900°C stage with X-Y and tilt control
- Laser raster (enhanced uniformity)
- O₂ environment w. pressure control



Why PLD?

- Very high KE of deposition flux
- Advantageous for complex oxide films: YBCO, STO, VO₂
- Relatively easier to maintain stoichiometry
- Tradeoff with uniformity



RHEED analysis

In-situ monitoring of film morphology

- Pattern gives clues as to growth model/type
- Intensity oscillation used to monitor thickness





EXTRA RAC RESOURCE - CONTOUR 3D PROFILER







Red Light



White Light





Non-contact profiler

- 3 nm resolution in VSI mode
 - Step height limited only by objective and microscope stage
- 0.1 nm resolution in PSI mode
 - Step height $<\lambda/4$ or 130 nm

Why Contour?

- No contact
- Fast
- Very high Z resolution

Example applications

Suitable for:

- Micron scale devices
- Microelectromechanical systems (MEMS)
- Gently varying optical features, lenses





INERT ATMOSPHERE FABRICATION LAB

2024



UNIVERSITY OF WATERLOO

Prepared by Taso Alkiviades

Transformative Quantum Technologies



Our goal is to extend our core facility platform into the 2D material device fabrication field and elevate the capabilities our 2D material research groups.





Guided by our core principals we developed a plan that encompasses the specific research requirements which were provided by Prof. Adam Wei Tsen and Dr. Tarun Patel and through our experience in designing professional lab spaces we set on developing a world class fabrication facility to serve our community.



Vision

Enabling world-class research via state-of-the-art facilities and professional operations

Mission

We are committed to operating a world-class nanofabrication and characterization facility to professional standards, to the combined benefit of the University of Waterloo's stakeholders, researchers and collaborators



TASK IN HAND

To develop a complete nanofabrication fabrication suit entirely integrated in an inert environment and include all the critical equipment pertaining to 2D material assembly



RUSSIAN NESTING DOLL – LEVEL OF INTEGRATION



APPROPRIATE FACILITY REQUIRMENTS

SPECIFY SICIENTIFIC EQUIPMENT

DESIGN OUR GLOVEBOX

INTEGRATE EQUIPMENT

TESTING OF EQUIP & PROCESS

PROCEDURES & TRAINING FRAMEWORK



KEY COMPONENTS OF INERT ATMOSPHERE FABRICATION LAB

- Nanofabrication equipment
- 2D Material assembly microscope
- Glovebox system







NPGS Software



Lithography System



Dr. Lino Eugene Nanofabrication and process engineer -QNFCF



Dr. Greg Holloway Electron Beam lithography Scientist - QNFCF

Requirements

To write micron scale features for generating electrical contacts to interface with our 2D flakes and it needed to be a maskless lithography system to generate custom patterns.

Design Specifications

JEOL IT510 scanning electron microscope, couples with a Nanometer pattern Generation System. 500nm features to date.

SEM

• 30KV Tungsten filament electron gun

- 5 Axis stage
- Large sample chamber, up to 2" wafers
- A user-friendly software interface

NPGS

- 16bit DAC
- Deben beam blanker 50nS
- Keithley 6485, Pico ammeter



NPGS

Joe Napaity, Nanometer Pattern Generation System

JEOL IT510 SEM



Mixing concrete for SEM base

Tong Liu, Chief Service Engineer, JEOL USA

JEOL IT510 Delivery

Mating JEOL IT510 to glovebox day

Our team has years of experience in Nanofabrication and can tailor the exact equipment to the process

Metal Deposition



Dr. Nathan Nelson Fitzpatrick, Director - QNFCF



System requirements

Capable of depositing thin films of Ti, Pd, Al, Ni and Au, to metalize our contacts.

System Specifications

Angstrom engineering NextDep thermal evaporator with dual door access via glovebox and standard atmosphere.

- 4-source thermal evaporator with single cooled source for long and rapid deposition rates in high melting point material
- Rotating heated substrate stage at 50RPM and 300°C
- 2x –cooled QCM deposition monitors
- We are currently setup for Au, Ti and Ni







OLYMPUS[®]

QNFCF has access multiskilled individuals who have come together to recreate and create new capabilities



2D Materials assembly microscope



Prof. Adam Wei, Tsen Associate Professor



Dr. Tarun Patel Postdoctoral Researcher



System requirements

"Pick and Place" 10-200µm 2D material flakes in order to stack them or place them on electrical contacts.

System Specifications

Vacuum stage with ultra fast heating for substrates and devices at 60°C per min up to 200°C. Micromanipulator with 62.5 nm/step precision. Vibration isolation platform.



AFM Characterization



Dr. Sandra Gibson, Nanofabrication and Characterization Scientist -QNFCF



Integration of existing characterization tools into the inert glovebox environment.

System Specifications

Characterize 2D material repeatedly measure up to 0.3nm in step height in inert environment

- Large area scanner 90 μm x 90 $\mu m,$ Z-range 7.5 μm
- Small area scanner 5 μm x 5 $\mu m,$ Z-range 1.5 μm







Glove Box

System requirements

The goal is to perform device fabrication in a stable inert environment to protects air sensitive material from oxidising. Allows multiple users to working on the system simultaneously

System Specifications

- 2x Quick load antechamber
- 2x large antechamber for bulk items
- Angstrom custom design doors to interface with large vacuum chamber equipment
- Two zone purification purification systems
 - Fabrication zone includes solvent scrubber













John Nugent, Making custom glovebox feedthroughs

De



Leighvi Batte, Assembly Technician, Angstrom Engineering



Scott Flynn, Test & Process Specialist, Angstrom Engineering



Andre Labelle, Test & Process Manager, Angstrom Engineering



Transformative **Quantum** Technologies



UNIVERSITY OF WATERLOO



THANK YOU ANGSTROM ENGINEERING

RAC1 – CLEAN ASSEMBLY LAB

6/12/24

John Nugent, Quantum Nano Fabrication and Characterization Facility





CLEAN ROOM



Clean Room

975 sq ft ISO 7 (Class 10,000)



Assembly Stations

ESD Safe clean assembly



Thermal Chamber

Test feedthrough -73C to 200C



WET CHEMISTRY



Solvents

General purpose, cleaning and prep



Acids & Bases

Acid or base processes, non-HF



Hydrofluoric Acid

Wet silicon oxide etch, HF solutions only



FABRICATION TOOLS



Diamond Saws

Precision, low speed <300rpm



Optical Microscopes

Leica, 5x-100x Bright/Dark Field EvoVision Stereo



Wire Bonder

45deg wedge 25-micron aluminum or gold wire



UNIVERSITY OF WATERLOO





Our greatest impact happens together.

ADDITIONAL RAC1/RAC2 RESOURCES

2024

UNIVERSITY OF

Scientaomicron LT-SPM LAB

- STM with QPLUS AFM option
- Location: RAC 2 Room 1124



SCANNING TUNNELING MICROSCOPY

STM principle of operation

The tunneling current is highly sensitive to sample topography (i.e. z) and the local density of states (LDOS) of the sample.



- Atomic-scale imaging
- Probing of novel quantum states

CRYOGENIC UHV SCANNING CHAMBER

Ultra-low vibrations
(isolation + low temperature)
3 scanner calibrations:

Room T, 77 K (LN2) and 5 K (LHe)

- Piezo scanner with ${\sim} \mathrm{pm}$ level stability
 - Sub-nA current amplifier

Rotating cryostat door access



UHV PREPARATION CHAMBER

- Resistive heating stage
- Direct current annealing (specialized sample holder)
- Argon-ion RF sputtering gun
- In-situ sample cleaving tool

- Remove contamination/oxidation
- Surface reconstructions



Si(111) 7x7

EXAMPLE RESULTS - STANDARDS



Terraces of Au (111) on Mica



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HOPG honeycomb lattice
(4 nm scale)
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HIGH RESOLUTION XRD



D8 Discover

Location: RAC 2
 Room 2112



THIN-FILM HR-XRD

- Cu-source X-ray tube
- Centric Eulerian-cradle

Psi, Phi and X-Y-Z translation

- 1 cm \square to 5" Ø wafers
- Vacuum chuck
- 1.0 x 6.0 mm beam





Film orientation/crystallinity

- Maintain $\omega = \frac{1}{2}(2\theta) + \text{offset}$
- Diffraction vector is always aligned \perp to substrate
- Peaks occur for all 'out-of-plane' *hkl* reflections



Ref: Harrington & Santiso, J. of Electroceramics (2021) 47:141–163

[400]

$(2\theta/\omega)$ Symmetric scan

Film orientation/crystallinity

- Maintain $\omega = \frac{1}{2}(2\theta) + \text{offset}$
- Diffraction vector is always aligned \perp to substrate
- Peaks occur for all 'out-of-plane' *hkl* reflections







$(2\theta/\omega)$ Symmetric scan

Film orientation/crystallinity

• Database of powder diffraction data for analysis







(XRD) Rocking Curve

The FWHM depends upon:

- the 'mosaic spread' of the grains
- density of dislocations
- substrate curvature



(XRR) REFLECTIVITY SCAN

- Measure X-ray intensity at grazing incidence
- Crystalline <u>or</u> amorphous film stacks
- Model oscillations to extract film properties
- \sim nm to 1 μ m thick



Substrate

Film Thickness

(XRR) REFLECTIVITY SCAN

- Measure X-ray intensity at grazing incidence
- Crystalline <u>or</u> amorphous film stacks
- Model oscillations to extract film properties
- \sim nm to 1 μ m thick

